INJ0003AX SERIES

PRELIMINARY

Notice: This is not a final specification Some parametric are subject to change High speed switching Silicon P-channel MOSFET

DESCRIPTION

INJ0003AX is a Silicon P-channel MOSFET.

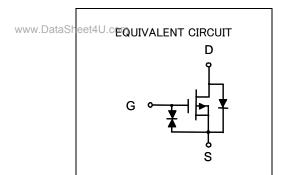
This product is most suitable for low voltage use such as portable machinery, because of low voltage drive and low on resistance.

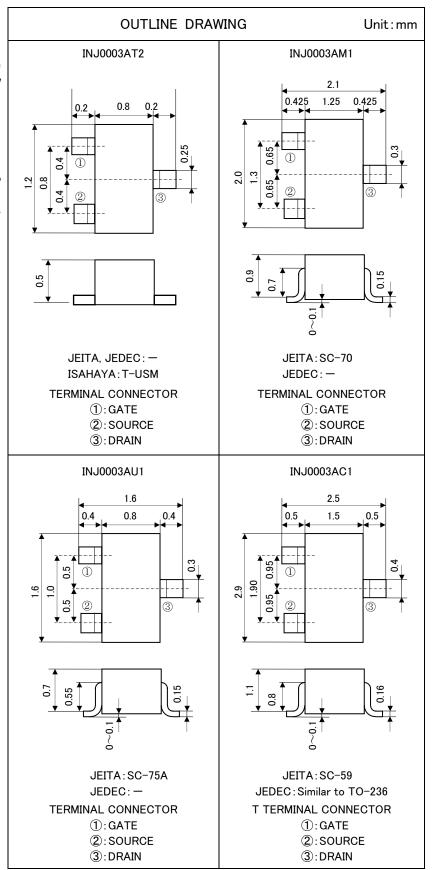
FEATURE

- •Input impedance is high, and not necessary to consider a drive electric current.
- •Vth is low, and drive by low voltage is possible. Vth=-0.6~-1.2V
- •Low on Resistance. Ron= $2\Omega(TYP)$
- ·High speed switching.
- ·Small package for easy mounting.

APPLICATION

high speed switching, Analog switching





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MAXIMUM RATING(Ta=25°C)

SYMBOL	PARAMETER	RATING				
		INJ0003AT2	INJ0003AU1	INJ0003AM1	INJ0003AC1	UNIT
$V_{\scriptscriptstyle DSS}$	Drain-source voltage	-20				
V_{GSS}	Gate-source voltage	±8				
Ι _D	Drain current	-200				
P_{D}	Total power dissipation (Ta=25°C)	125(※)	150	200		mW
Tch	Channel temperature	+125	+150			°C
Tstg	Range of Storage temperature	−55 ~ +125	−55 ~ +150			°C

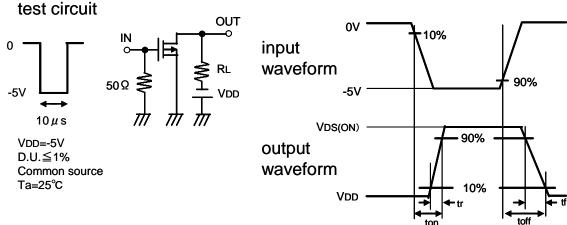
ELECTRICAL CHARACTERISTICS (Ta=25°C)

%package mounted on 9mm \times 19mm \times 1mm glass-epoxy substrate.

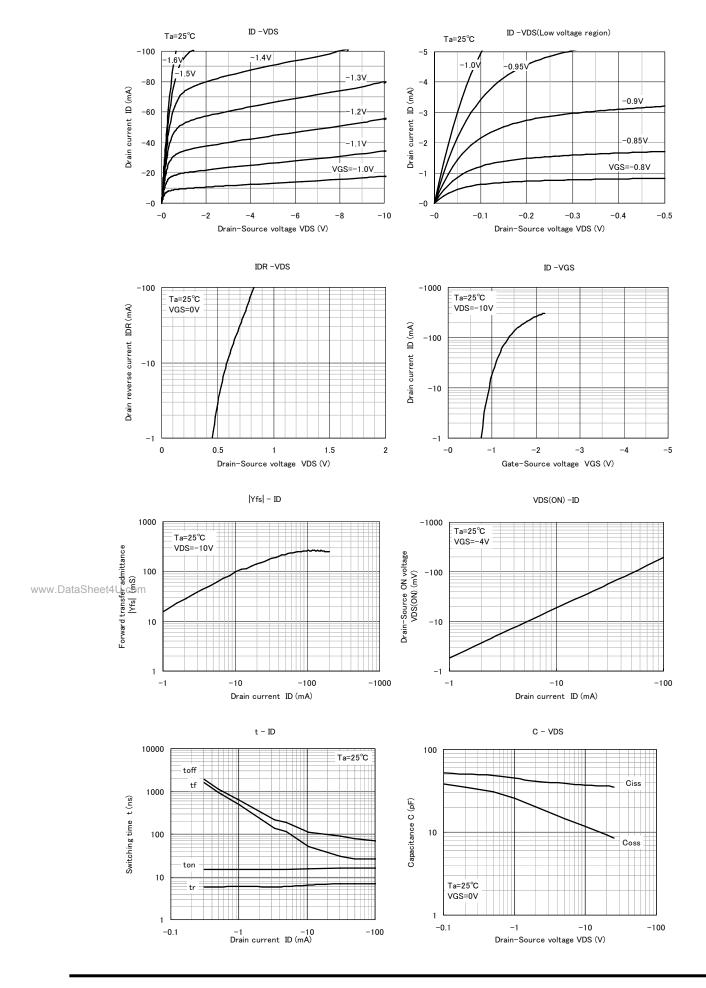
SYMBOL	PARAMETER	TEST CONDITION	LIMIT			LINIT
			MIN	TYP	MAX	UNIT
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_{D} = -100 \mu \text{ A}, V_{GS} = 0V$	-20	_	_	V
I _{GSS}	Gate-source leak current	$V_{GS} = \pm 5V, V_{DS} = 0V$	_	-	±0.5	μΑ
I _{DSS}	Zero gate voltage drain current	V _{DS} =-20V ,V _{GS} =0V	_	-	-50	μΑ
V_{th}	Gate threshold voltage	I $_{D}$ =-250 μ A, V $_{DS}$ = V $_{GS}$	-0.6	_	-1.2	٧
Y _{fs}	Forward transfer admittance	V _{DS} =-10V, I _D =-0.1A	_	280	-	mS
R _{DS(ON)}	Static drain-source on-state resistance	I _D =-100mA, V _{GS} =-4.0V	-	2	-	Ω
Ciss	Input capacitance	V _{DS} =-10V, V _{GS} =0V,f=1MHz	_	37	-	pF
Coss	Output capacitance	V _{DS} =-10V, V _{GS} =0V,f=1MHz	_	12	-	pF
ton	- Switching time	V_{DD} =-5 V , I_{D} =-10mA	_	16	-	
toff		V _{GS} =0~-5V	_	110	-	ns

Switching time test condition

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TYPICAL CHARACTERISTICS





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